



JST06A-600C 6A TRIAC

Rev.A.1.0

DESCRIPTION:

The JST06A-600C triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. By using an internal ceramic pad, JST06A-600C provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TO-220A is RoHS compliant.

MAIN FEATURES

Symbol

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-125	
Repetitive peak off-state voltage ($T_j=25^\circ C$)	V_{DRM}	600	V
Repetitive peak reverse voltage ($T_j=25^\circ C$)	V_{RRM}	600	V
RMS on-state current ($T_c = 100^\circ C$)	$I_{T(RMS)}$	6	A
Non repetitive surge peak on-state current (full cycle , $t_p=20ms$, $T_j=25^\circ C$)	I_{TSM}	65	A
Non repetitive surge peak on-state current (full cycle , $t_p=16.6ms$, $T_j=25^\circ C$)		72	
I^2t value for fusing ($t_p=10ms$, $T_j=25^\circ C$)	I^2t	21	A^2s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$, $f=100Hz$, $T_j=125^\circ C$)	- -	80 40	$A/\mu s$
Peak gate current ($t_p=20\mu s$, $T_j=125^\circ C$)			
Average gate power dissipation ($T_j=125^\circ C$)	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	10	W

Peak pulse voltage (T _j =25 °C; non-repetitive, off-state; FIG.7)	V _{PP}	5	kV
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ELECTRICAL CHARACTERISTICS (T_j=25 °C unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I _{GT}	V _D =12V R _L =33	- -	MAX.	25	mA
				50	
V _{GT}		ALL	MAX.	1	V
V _{GD}	V _D =V _{DRM} T _j =125 °C R _L =3.3K	ALL	MIN.	0.2	V
I _L	I _G =1.2I _{GT}	- -	MAX.	50	mA
				60	
I _H	I _T =200mA		MAX.	40	mA
dV/dt	V _D =400V Gate Open T _j =125 °C		MIN.	400	V/μs
(dV/dt)c	(dI/dt)c=2.7A/ms, T _j =125 °C		MIN.	5	V/μs
t _{on}	I _G =80mA I _A =400mA I _R =40mA T _j =25 °C	TYP.	3	μs	
t _{off}			30		

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V _{TM}	I _{TM} =8.5A t _p =380μs	T _j =25 °C	1.5	V
V _{TO}	Threshold voltage	T _j =125 °C	0.82	V
R _D	Dynamic resistance	T _j =125 °C	57	mΩ
I _{DRM}	V _D =V _{DRM} V _R =V _{RRM}	T _j =25 °C	5	μA
I _{RRM}		T _j =125 °C	0.2	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th(j-c)}	junction to case (AC)	3	/W
R _{th(j-a)}	junction to ambient (AC)	60	/W

ORDERING INFORMATION

J	ST	06	A	-600	C
JieJie Microelectronics Co., Ltd.					
	Triacs				
		IT(RMS):6A			
			A:TO-220A(Ins)		
				600:V _{DRM} /V _{RRM} 600V	
					C:IGT1-3 25mA IGT4 50mA

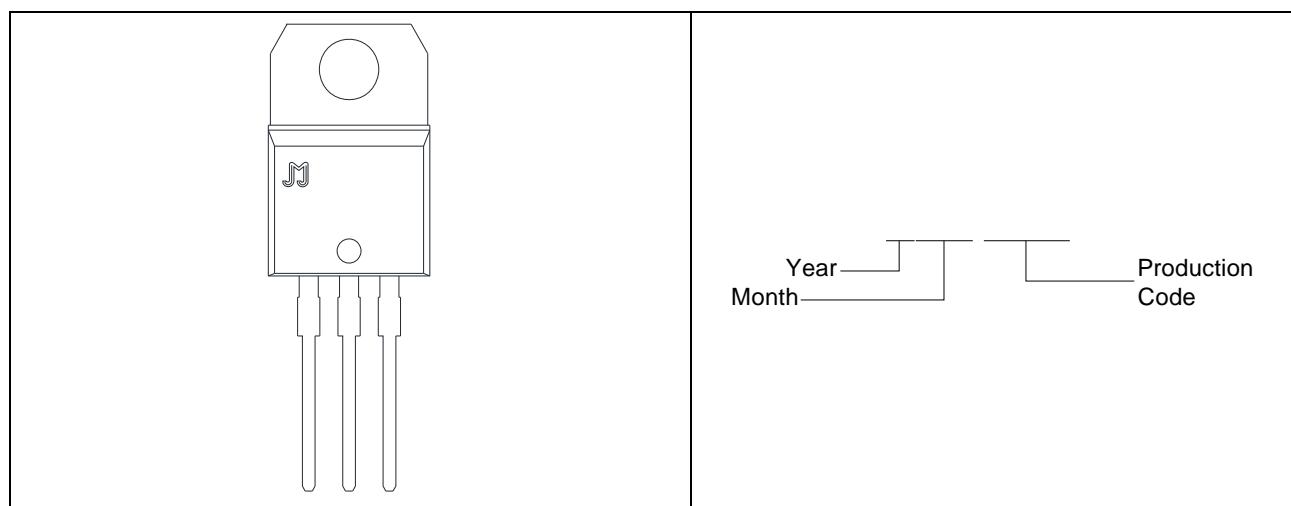
MARKING

FIG.1 Maximum power dissipation versus RMS on-state current

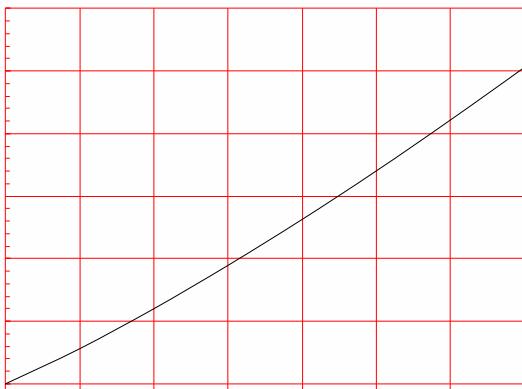


FIG.2: RMS on-state current versus case temperature

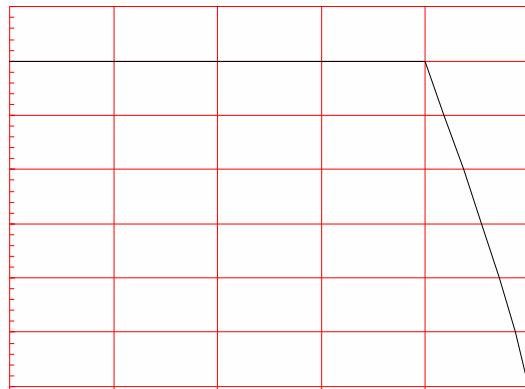


FIG.3: Surge peak on-state current versus number of cycles

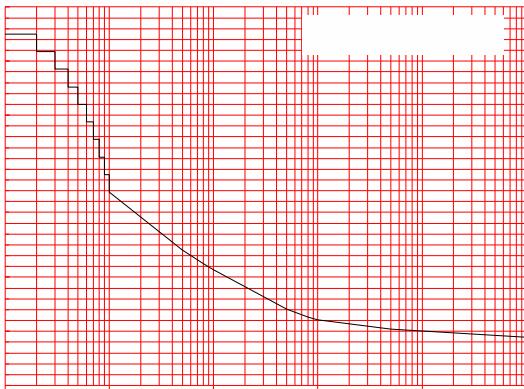


FIG.4: On-state characteristics

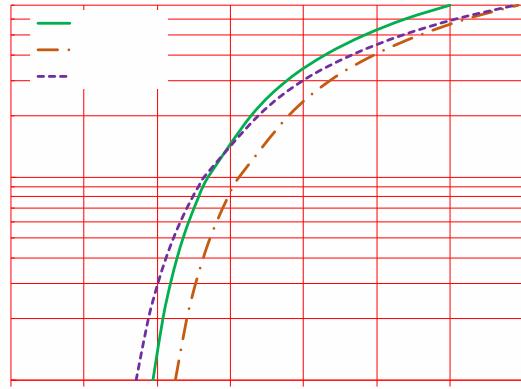


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I^2t (- : $dI/dt < 80\text{A}/\mu\text{s}$; - : $dI/dt < 40\text{A}/\mu\text{s}$)

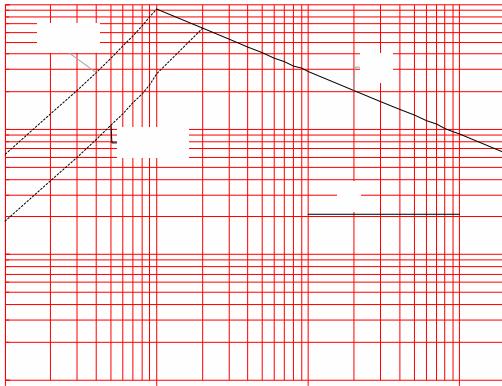
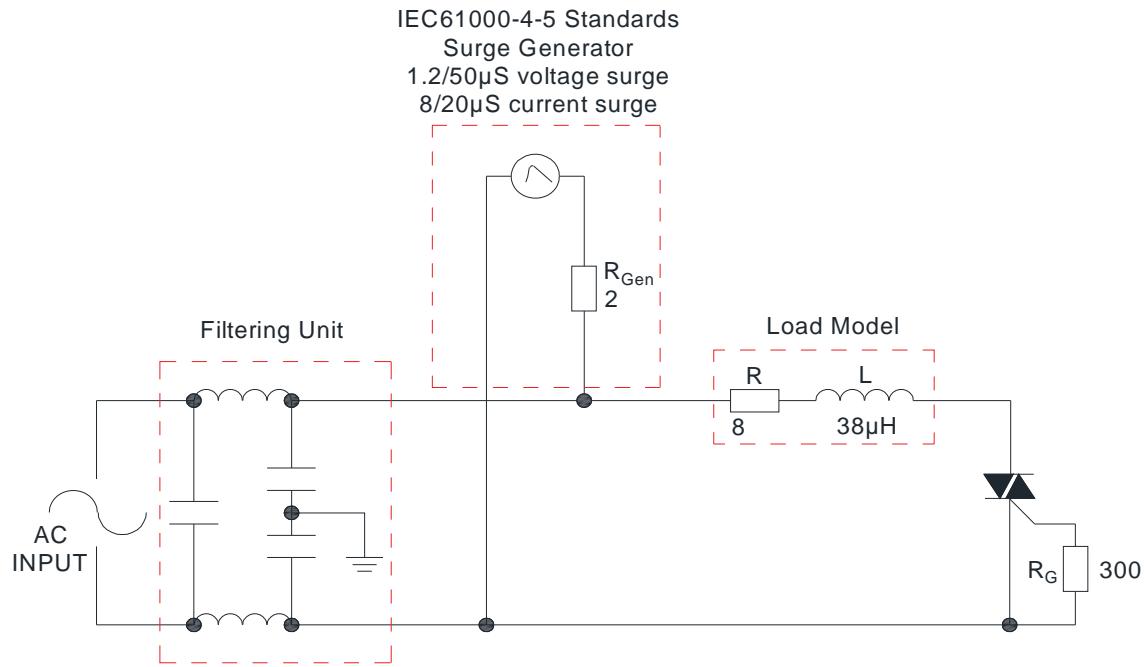


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



SHAPING AND SOLDERING PARAMETERS

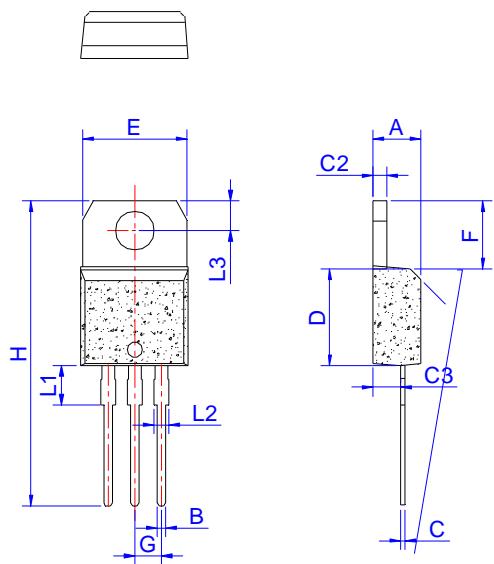
Refer to Instructions for installation of plastic-sealed in-line power devices released by JieJie.

ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)		Package	Base qty. (pcs)	Delivery mode
		-	-			
JST06A-600C	600	25	50	TO-220A(Ins)	50	Tube

Document Revision History

Date	Revision	Changes
Apr.14, 2023	A.1.0	Last updated

PACKAGE MECHANICAL DATA

JST06A-600C

JieJie Microelectronics CO., Ltd.